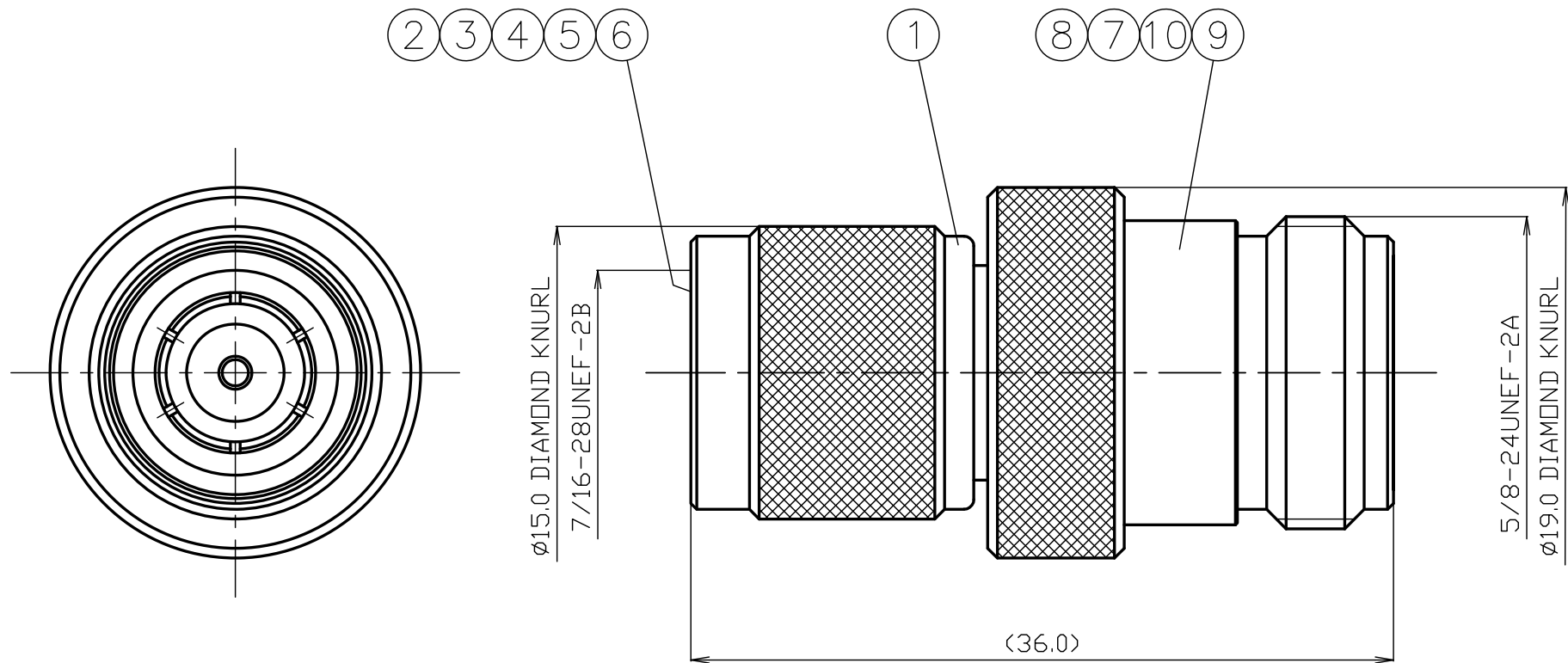




※1:PHOSPHOR BRONZE

10	BUSHING	BRASS	1	Ni	
9	BODY	BRASS	1	Ni	
8	CENTER PIN	※1	1	Au	
7	INSULATOR B	PTFE	1	--	
6	FLAT WASHER	BRASS	1	Ni	
5	SPACER	POM	1	--	
4	HALF FLAT WASHER	BRASS	2	Ni	
3	GASKET	SILICONE	1	--	
2	INSULATOR A	PTFE	1	--	
1	SHELL	BRASS	1	Ni	
NO.	DESCRIPTION	MATERIAL	Q'TY	FINISH	REMARK

RoHS Compliant Cd ≤75ppm

REMARKS BRASS: Cd ≤75ppm
PHOSPHOR BRONZE: Pb <4wt%

SCALE 3/1

UNIT mm

DATE 2023.03.22

DRAWN	CHECKED	APPROVED	CONFIRMATION	PART NUMBER
渡邊 '23.03.22 直弘	檜 '23.03.22 澤	山 '23.03.22 本	三 '23.03.22 村	TNCP-NJ
PROJECTION				DRAWING NO. R-0670737
				

PRODUCT SPECIFICATION

Part number: TNCP-NJ

No. 0670116

Drawing number: R-0670737

Nominal 1 Standard

MIL C 39012(TNC)

MIL C 39012,JIS C 5411(N)

2 Voltage Rating

AC 500V

3 Frequency Range

4GHz

4 Impedance

50Ω

5 Operating Temperature Range -40°C~+85°C



株式会社 トーコネ
TO-CONNE CO.,LTD.

	Test Items	Procedures/Test Method	Requirements
1	Design and Construction	Specified on relevant product drawing (Drawing number: R-0670737)	No defects or abnormalities
2	Materials		
3	Finish		
4	Insulation Resistance	DC 500V	1000 MΩ (Min.)
5	Withstand Voltage	1 minute at AC 1000V	No defects or abnormalities
6	Contact Resistance	The method of which, the voltage drop of the contact duration should not exceed about 1-kHz AC or 1mV DC	3mΩ (Max.)
7	V.S.W.R	DC ~ 2GHz	1.2 (Max.)
8	Compatibility	Mating with connector complying with the standard	No defects or abnormalities
9	Center contact captivation	When axial tensile force of 4.9N is applied	No defects or abnormalities
10	Engagement Force(N)	When axial tensile force of 294N is applied	Threads should have no abnormalities
11	Center contact mating force(N)	0.98N (Min.) when using the standard pin gauge	No defects or abnormalities
12	Number of matings	After 5000 matings	Contact resistance 10mΩ(Max.)
13	Corrosion Resistance	After continuous exposure to salt spray with neutral 5% salt water for 48 hours. The center contact after 10 matings.	Withstand voltage must satisfy the requirements listed in item 5 and the contact resistance is under 50mΩ

	REVISIONS	DATE
1		
2		

Checked	Approved	Proof mark	Prepared
三 23.03.22 村	山 23.03.22 本	檜 23.03.22 澤	渡邊 '23.03.22 直弘

GKQM-7